

SILICON TRANSISTOR ARRAY μ PA1437

PNP SILICON POWER TRANSISTOR ARRAY LOW SPEED SWITCHING USE (DARLINGTON TRANSISTOR) INDUSTRIAL USE

DESCRIPTION

The μ PA1437 is PNP silicon epitaxial Darlington Power Transistor Array that built in 4 circuits designed for driving solenoid, relay, lamp and so on.

FEATURES

- · Easy mount by 0.1 inch of terminal interval.
- High hee for Darlington Transistor.

ORDERING INFORMATION

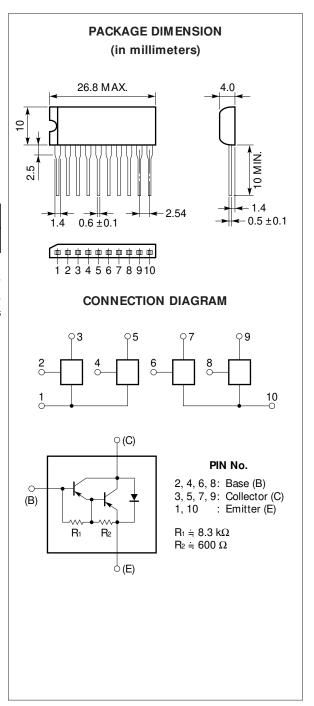
Part Number	Package	Quality Grade
μPA1437H	10 Pin SIP	Standard

Please refer to "Quality grade on NEC Semiconductor Devices" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

ABSOLUTE MAXIMUM RATINGS (Ta = 25 °C)

Collector to Base Voltage	Vсво	-100	V
Collector to Emitter Voltage	VCEO	-100	V
Emitter to Base Voltage	V_{EBO}	- 7	V
Collector Current (DC)	Ic(DC)	∓3	A/unit
Collector Current (pulse)	$I_{C(pulse)}^{*}$	∓ 6	A/unit
Base Current (DC)	$I_{B(DC)}$	-0.3	A/unit
Total Power Dissipation	P _{T1} **	3.5	W
Total Power Dissipation	PT2* * *	28	W
Junction Temperature	T_{j}	150	°C
Storage Temperature	T _{stg} -55	to +150) °C

- * PW \leq 300 μ s, Duty Cycle \leq 10 %
- ** 4 Circuits, Ta = 25 °C
- *** 4 Circuits, Tc = 25 °C



The information in this document is subject to change without notice.

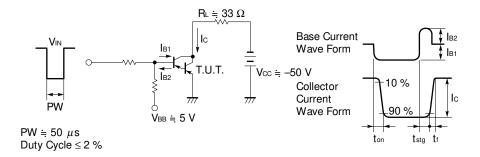


ELECTRICAL CHARACTERISTICS (Ta = 25 °C)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Collector to Emitter Sustaining Voltage	VCEO(SUS)	-100			V	Ic = -1.5 A, IB = -1.5 mA, L = 1 mH
Collector Leakage Current	Ісво			-10	μΑ	Vcb = -100 V, IE = 0
Emitter Leakage Current	I _{EBO}			-1	m A	V _{EB} = -5 V, I _C = 0
DC Current Gain	h _{FE1} *	1000			_	Vce = -2 V, Ic = -0.5 A
DC Current Gain	h _{FE2} *	2000		20000	_	Vce = -2 V, Ic = -1.5 A
Collector Saturation Voltage	VCE(sat) *		-0.9	-1.2	V	$Ic = -1.5 A$, $I_B = -1.5 mA$
Base Saturation Voltage	V _{BE(sat)} *		-1.5	-2	V	Ic = -1.5 A, I _B = -1.5 mA
Turn On Time	ton		1		μs	Ic = -1.5 A
Storage Time	tstg		3		μs	$I_{B1} = -I_{B2} = -1.5 \text{ mA}$ $V_{CC} \doteq 50 \text{ V}, \text{ RL} \doteq 33 \Omega$ See test circuit
Fall Time	t f		1		μs	

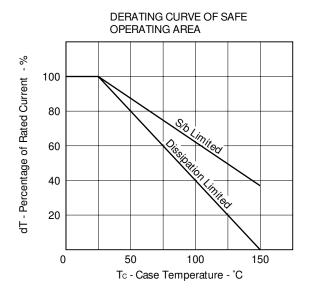
^{*} PW \leq 350 $\mu \text{s}, \; \text{Duty Cycle} \leq$ 2 % / pulsed

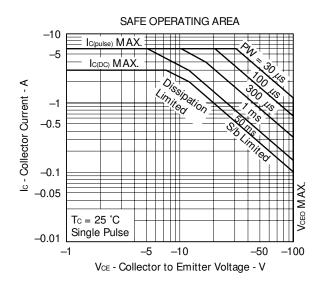
SWITCHING TIME TEST CIRCUIT

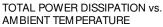


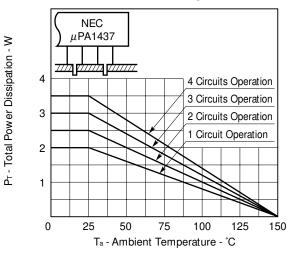


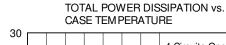
TYPICAL CHARACTERISTICS (Ta = 25 °C)

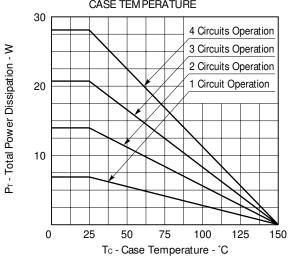


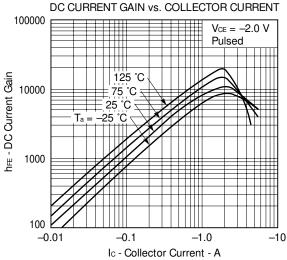




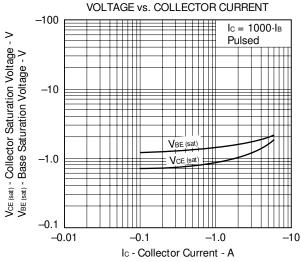




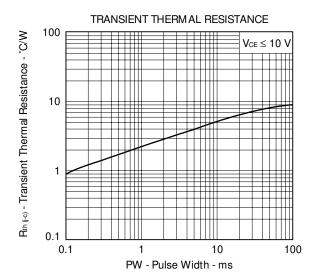


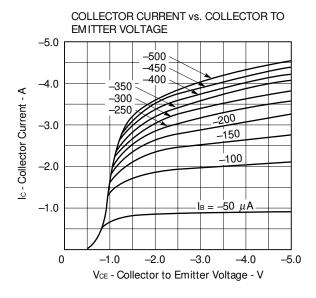


BASE AND COLLECTOR SATURATION











REFERENCE

Document Name	Document No.
NEC semiconductor device reliability/quality control system.	TEI-1202
Quality grade on NEC semiconductor devices.	IEI-1209
Semiconductor device mounting technology manual.	IEI-1207
Semiconductor device package manual.	IEI-1213
Guide to quality assurance for semiconductor devices.	M EI-1202
Semiconductor selection guide.	MF-1134

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